NSN 5961-01-359-1817

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-359-1817 **Inclosure Material:** Plastic **Overall Length:** Between 0.110 inches and 0.120 inches **Overall Height:** Between 0.033 inches and 0.047 inches **Overall Width:** Between 0.083 inches and 0.098 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Sot-23 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, dc **Current Rating Per Characteristic:** 100.00 milliamperes forward current, dc **Power Rating Per Characteristic:** 250.0 milliwatts off-state power dissipation **Capacitance Rating In Picofarads:** 0.35 **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig:

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